



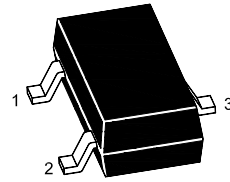
# MMBTSC3875

## NPN Transistor

### Features

- For Switching and AF Amplifier Applications.
- As Complementary Type of the PNP Transistor  
MMBTSA1504 is Recommended.

**SOT-23**  
**(TO-236)**



1.Base 2.Emitter 3.Collector

**Marking:**

**MMBTSC3875O:ALO**

**MMBTSC3875Y:ALY**

**MMBTSC3875G:ALG**

**MMBTSC3875L:ALL**

### Absolute Maximum Ratings

Ratings at 25°C ambient temperature unless otherwise specified.

Parameter	Symbol	Value	Unit
Collector Base Voltage	$V_{CBO}$	60	V
Collector Emitter Voltage	$V_{CEO}$	50	V
Emitter Base Voltage	$V_{EBO}$	5	V
Collector Current	$I_C$	150	mA
Power Dissipation	$P_D$	150	mW
Junction Temperature	$T_J$	150	°C
Storage Temperature Range	$T_{STG}$	-55 to 150	°C



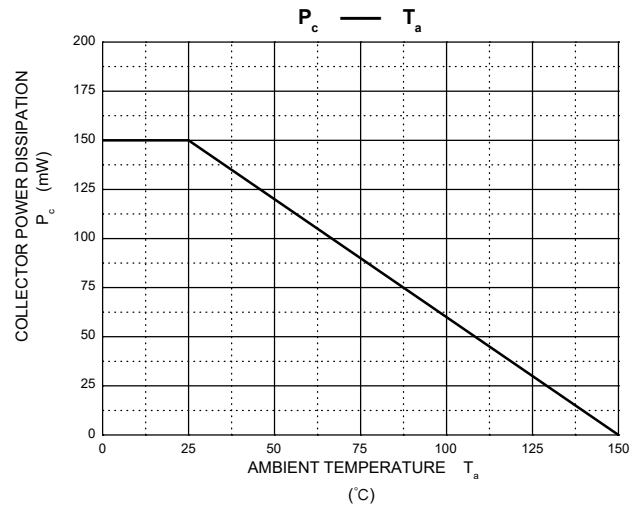
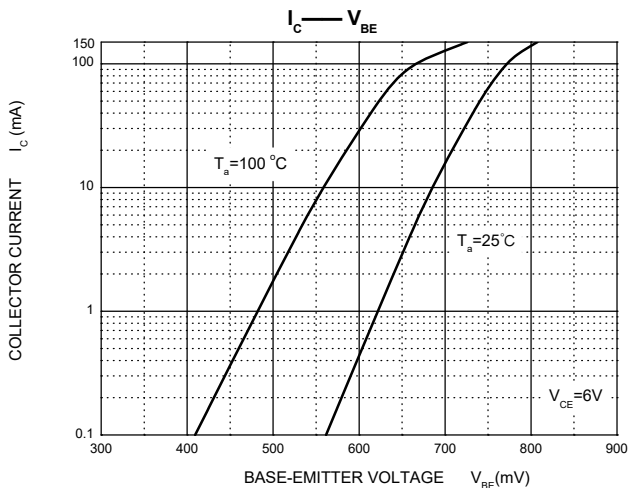
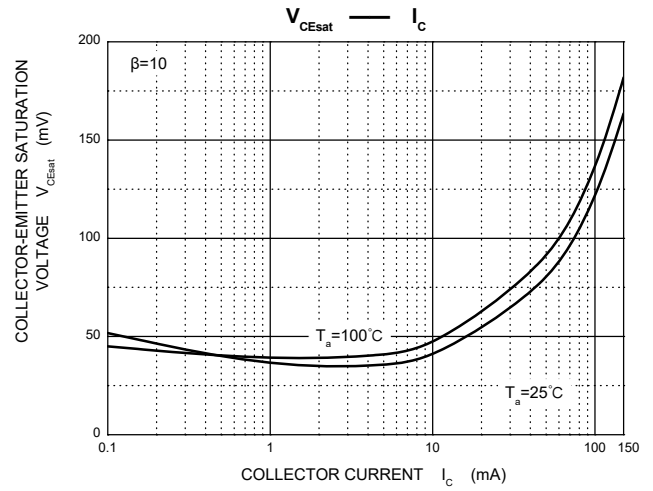
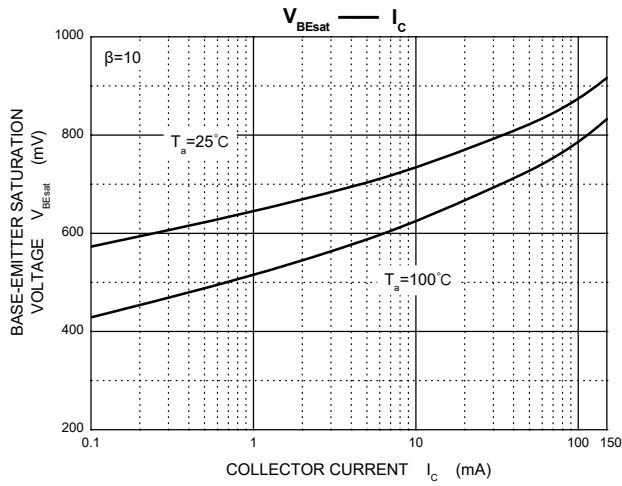
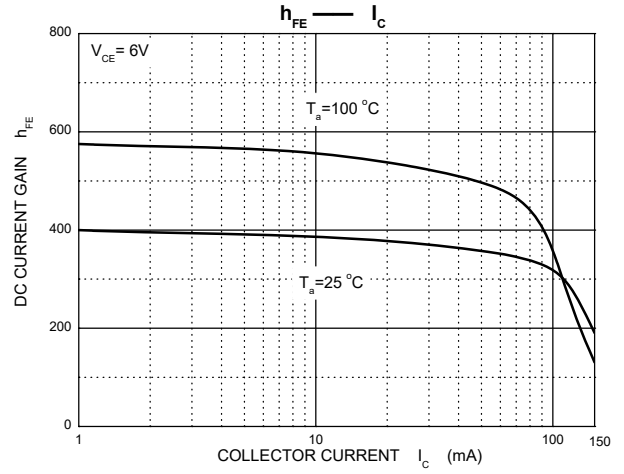
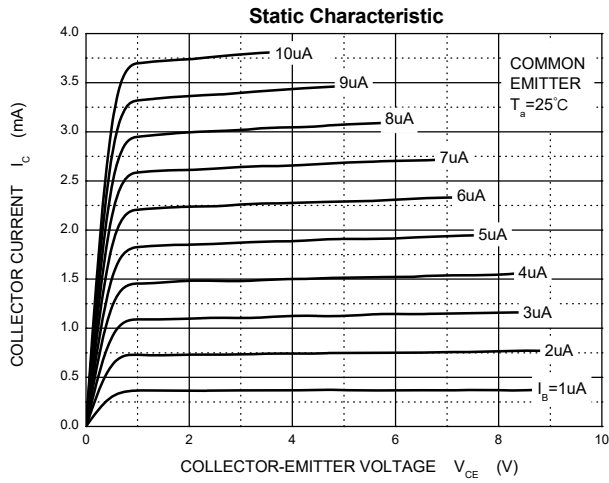
### Electrical Characteristics

Ratings at 25°C ambient temperature unless otherwise specified.

Parameter	Symbol	Min.	Typ.	Max.	Unit
DC Current Gain at $V_{CE} = 6\text{ V}$ , $I_C = 2\text{ mA}$ Current Gain Group	O Y G L  $H_{FE}$	70	-	140	
		120	-	240	
		200	-	400	
		350	-	700	
Collector Base Cutoff Current at $V_{CB} = 60\text{ V}$	$I_{CBO}$	-	-	100	nA
Emitter Base Cutoff Current at $V_{EB} = 5\text{ V}$	$I_{EBO}$	-	-	100	nA
Collector Base Breakdown Voltage at $I_C = 100\text{ }\mu\text{A}$	$V_{(BR)CBO}$	60	-	-	V
Collector Emitter Breakdown Voltage at $I_C = 1\text{ mA}$	$V_{(BR)CEO}$	50	-	-	V
Emitter Base Breakdown Voltage at $I_E = 100\text{ }\mu\text{A}$	$V_{(BR)EBO}$	5	-	-	V
Collector Emitter Saturation Voltage at $I_C = 100\text{ mA}$ , $I_B = 10\text{ mA}$	$V_{CE(sat)}$	-	0.1	0.25	V
Base Emitter Saturation Voltage at $I_C = 100\text{ mA}$ , $I_B = 10\text{ mA}$	$V_{BE(sat)}$	-	-	1	V
Transition Frequency at $V_{CE} = 10\text{ V}$ , $I_C = 1\text{ mA}$	$f_T$	80	-	-	MHz
Collector Base Capacitance at $V_{CB} = 10\text{ V}$ , $f = 1\text{ MHz}$	$C_{ob}$	-	-	3.5	pF

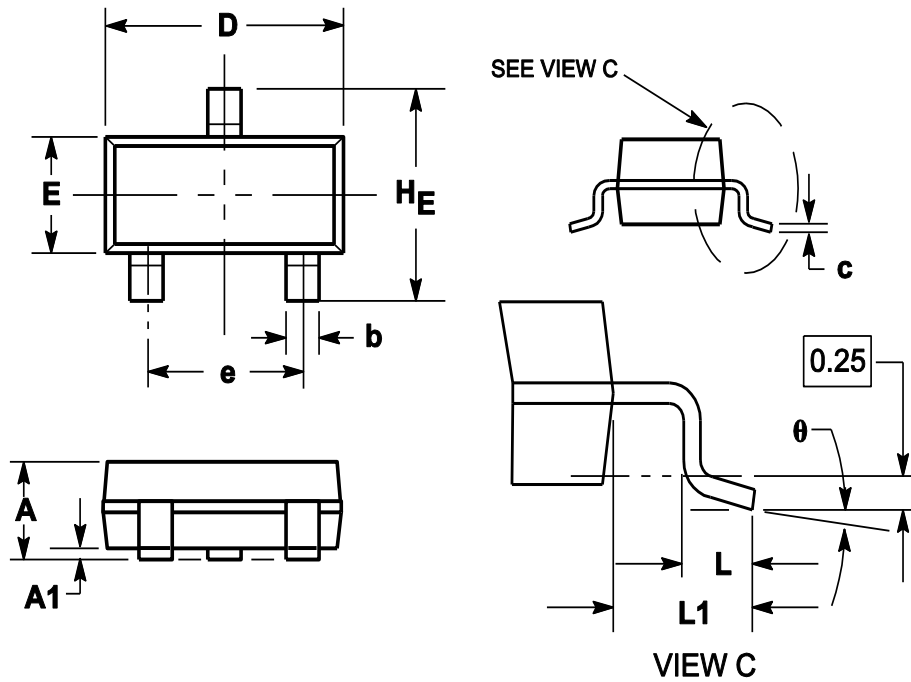


### Electrical Characteristics Curves





### Package Outline(SOT-23)



Symbol	Dimensions in millimeter		
	Min.	Typ.	Max.
A	0.900	1.025	1.150
A1	0.000	0.050	0.100
b	0.300	0.400	0.500
c	0.080	0.115	0.150
D	2.800	2.900	3.000
E	1.200	1.300	1.400
HE	2.250	2.400	2.550
e	1.800	1.900	2.000
L1	0.550REF		
L	0.300		0.500
$\theta$	0°		8°

### Ordering Information

Device	Package	Reel Dimension (inch)	Shipping
MMBTSC3875	SOT-23	7	3,000

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